



ASIC Development for Space Radiation Monitors at IDEAS

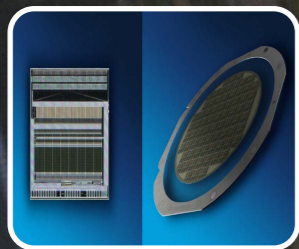
Integrated Detector Electronics AS

Presented to the European Space Plasma and Radiation Workshop, ESTEC, May 14 2014
Philip Pålsson, Development Engineer, philip.pahlsson@ideas.no

ASIC Development for Space Radiation Monitors at IDEAS



IDEAS company overview



ASIC Heritage and ASIC families



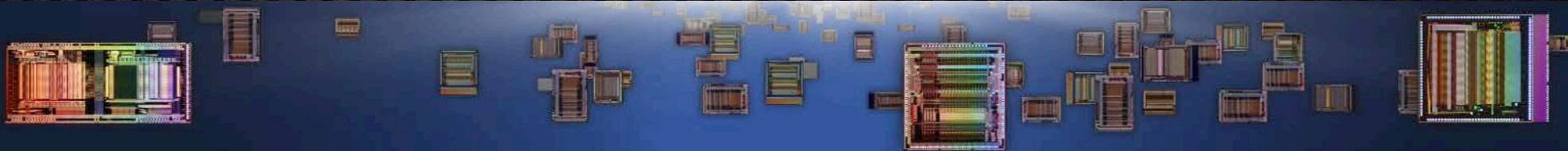
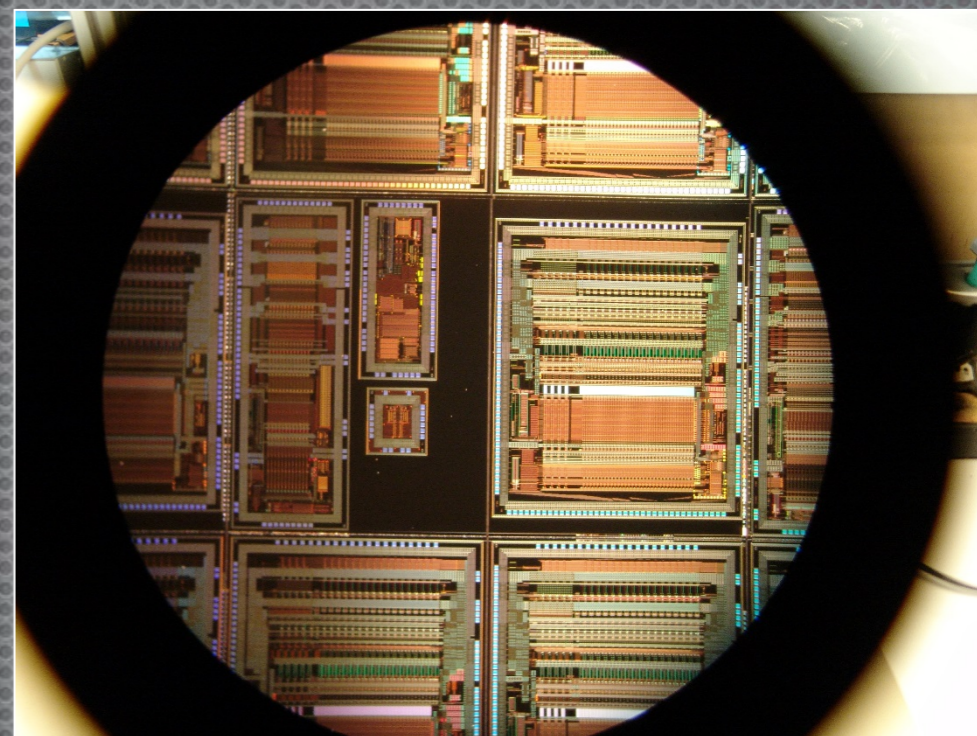
Selection of ASICs for space radiation and plasma monitoring

Integrated Detector Electronics AS

Presented to the European Space Plasma and Radiation Workshop, ESTE May 4 2014
Philip Pahlsson, Development Engineer, philip.pahlsson@ideas.no

IDEAS overview

IDEAS - Integrated Detector Electronics AS - develops and sells integrated circuits for radiation detection and imaging applications. The company was founded in 1992 with strong background in applied physics, radiation detector instrumentation and electrical engineering. The headquarter is located near Oslo, Norway. IDEAS products are used in medical imaging, industrial inspection, nuclear science and astrophysics. The circuits can be delivered in any quantity to commercial and scientific customers worldwide.



IDEAS staff

2 Ph.D. Physicists with Nuclear Science and HEP

1 Ph.D. Electronics Engineer, Digital Systems

6 M.Sc Integrated Circuit Designers

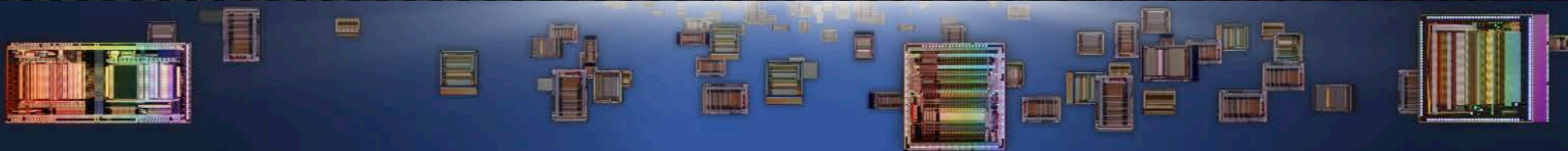
2 M.Sc Electronic Design Engineers

2 M.Sc Space Engineering

1 Electronic Design/Validation Engineer

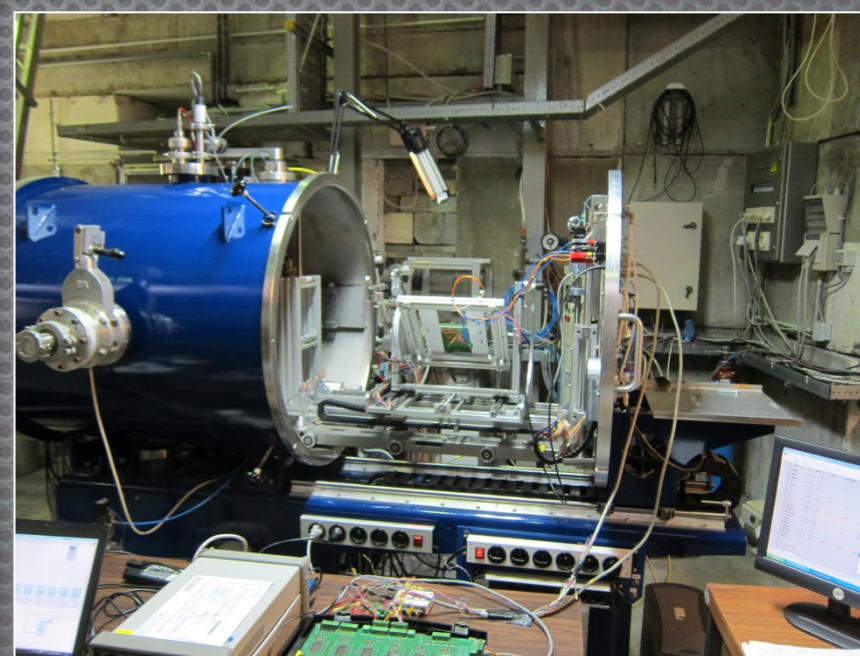
1 Technician

1 M.Sc. Senior Accountant



IDEAS validation

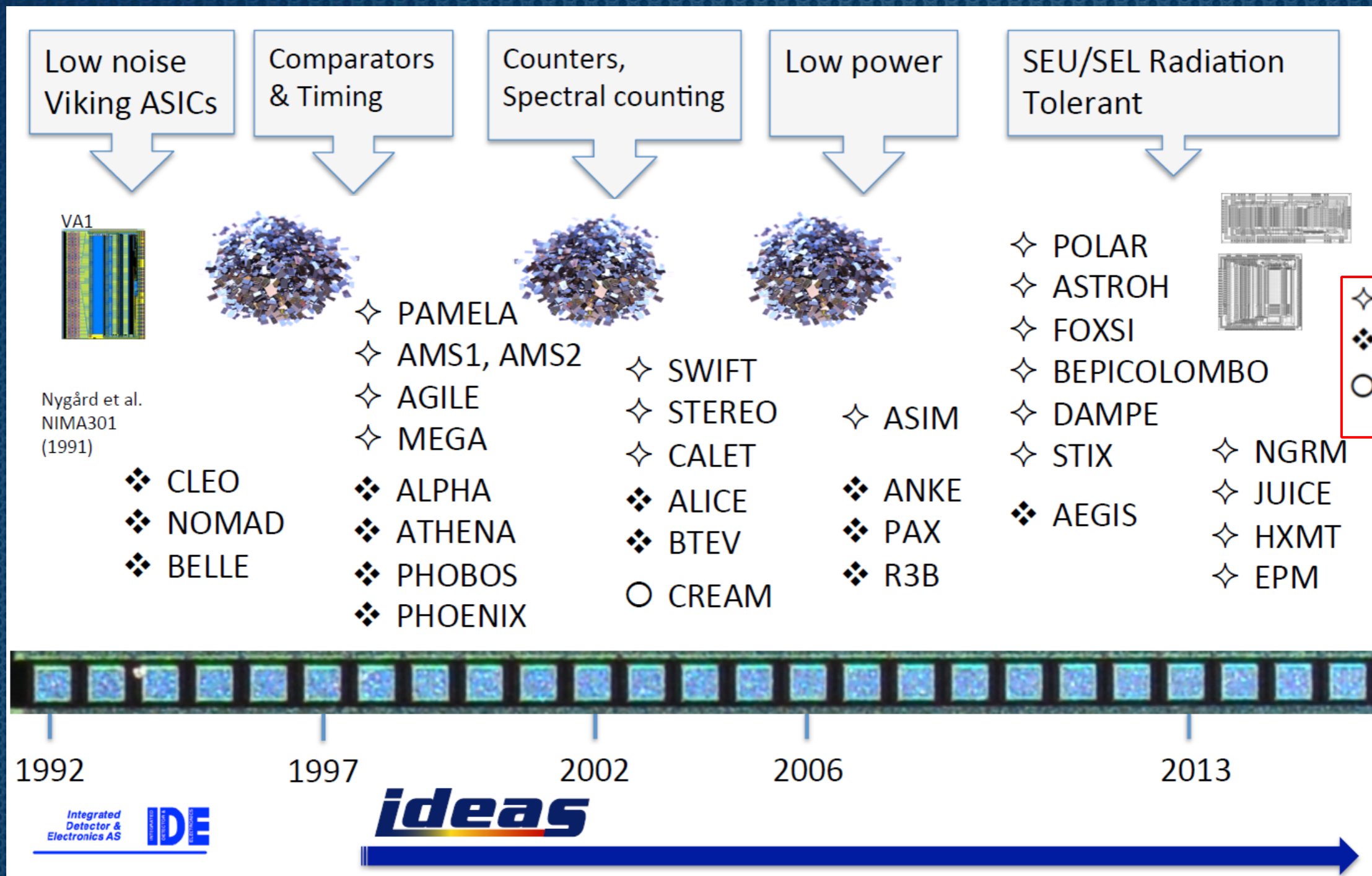
Temperature Chamber
 Cryogenic Dewar
 X-ray Source
 Radioactive sources



Validation	Standard
SEE	ESCC-25100
TID	ESCC-22900
SEM	ESCC-21400

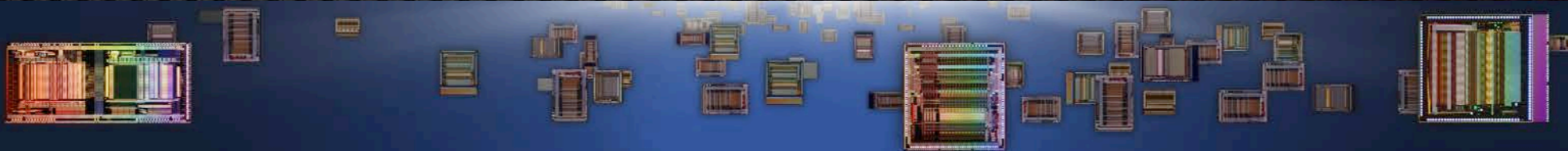


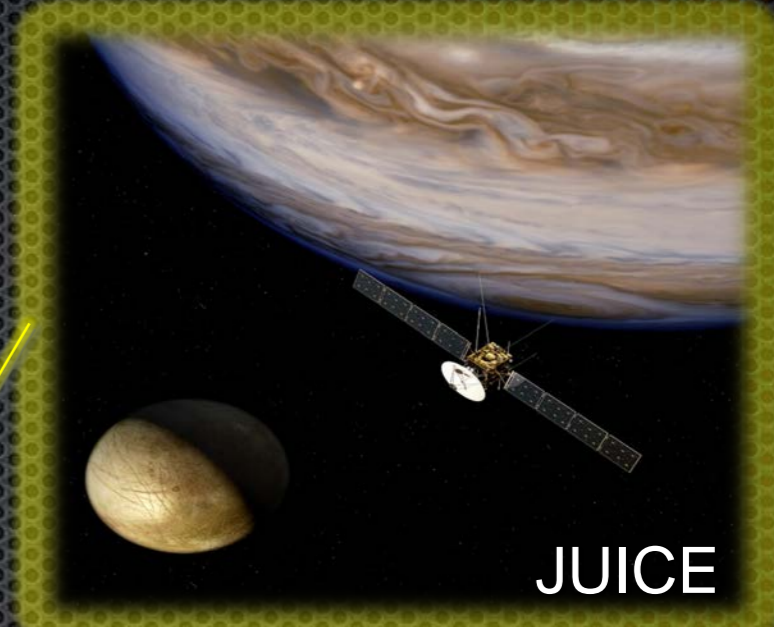
ASIC heritage for Science



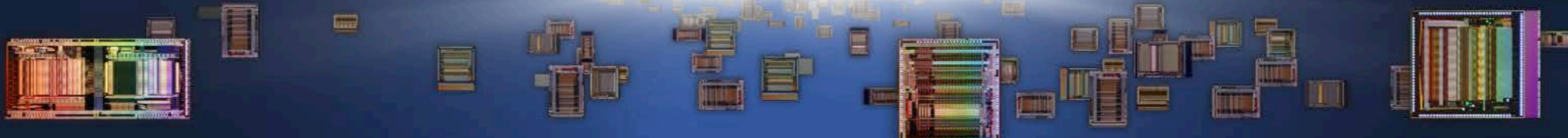
Selection of ASICs

ASIC	Application reference
IDE 3465 (VATA465)	NGRM
IDE 3466 (VATA466)	RADEM
IDE 4281 (XA281)	STIX
IDE 4183 (XA1.83)	ASIM
VA_SCM3.2	Dosimetry, Radiography, Portal Imaging



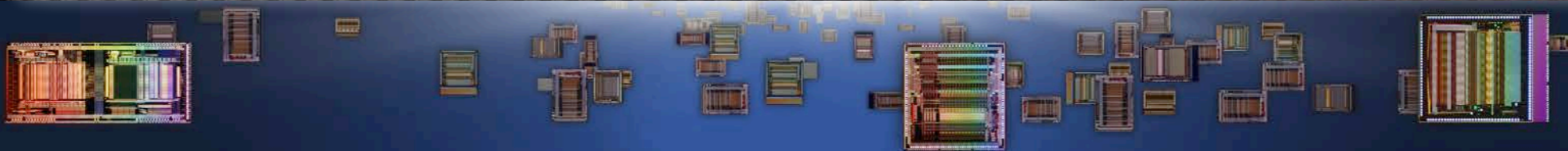
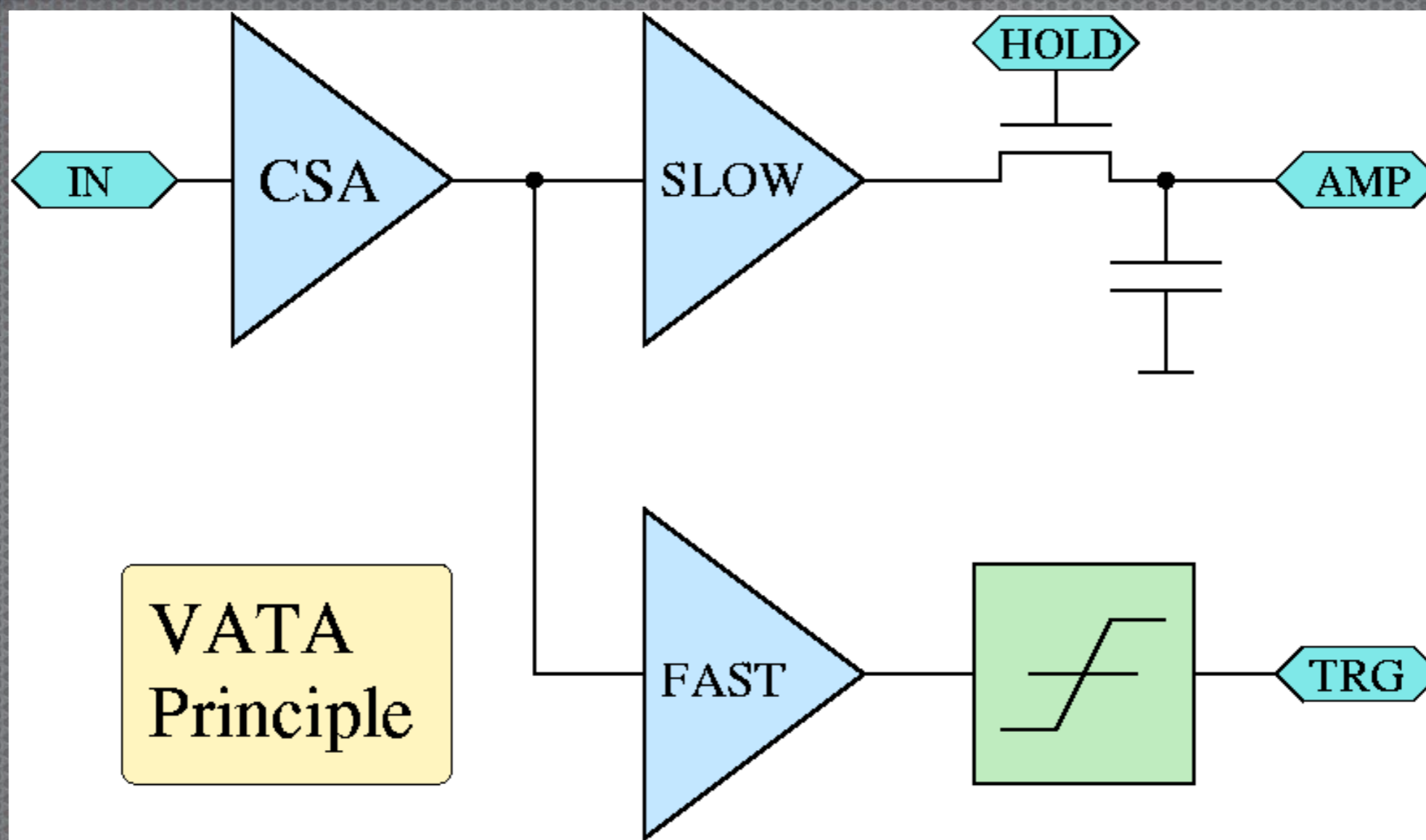


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VATA - family ASICs

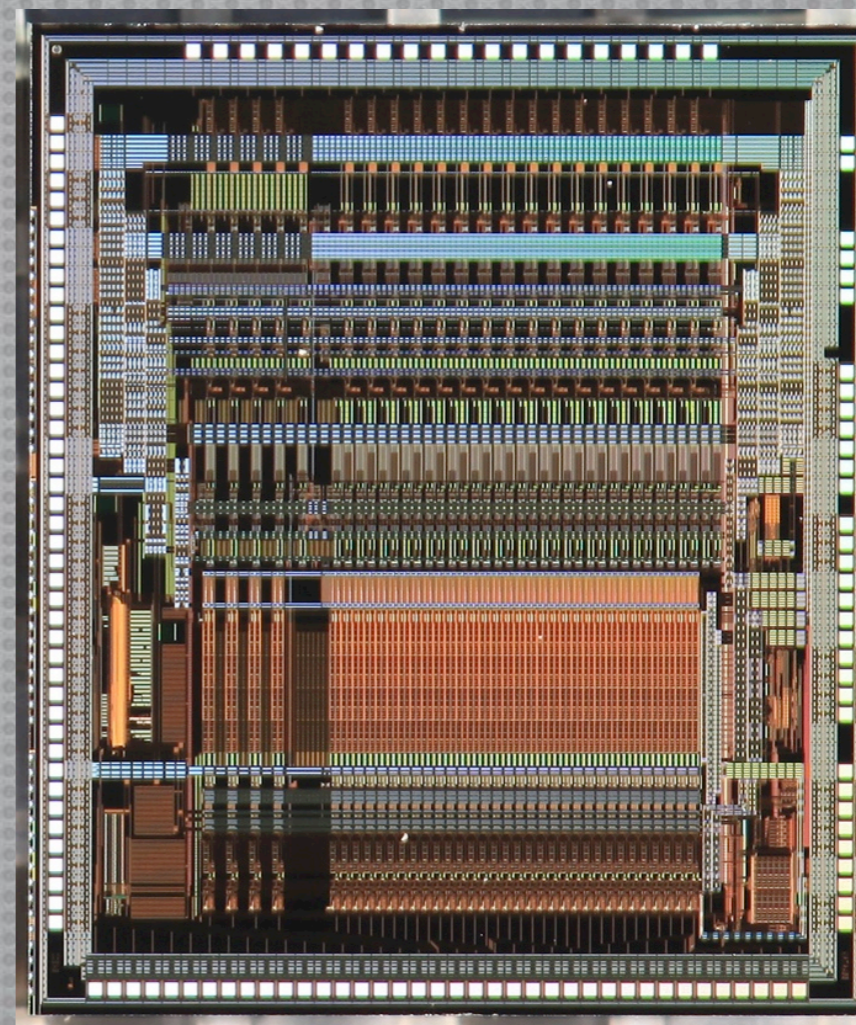
ASICs for spectroscopy with on-chip trigger, system driven



IDE 3465 – NGRM

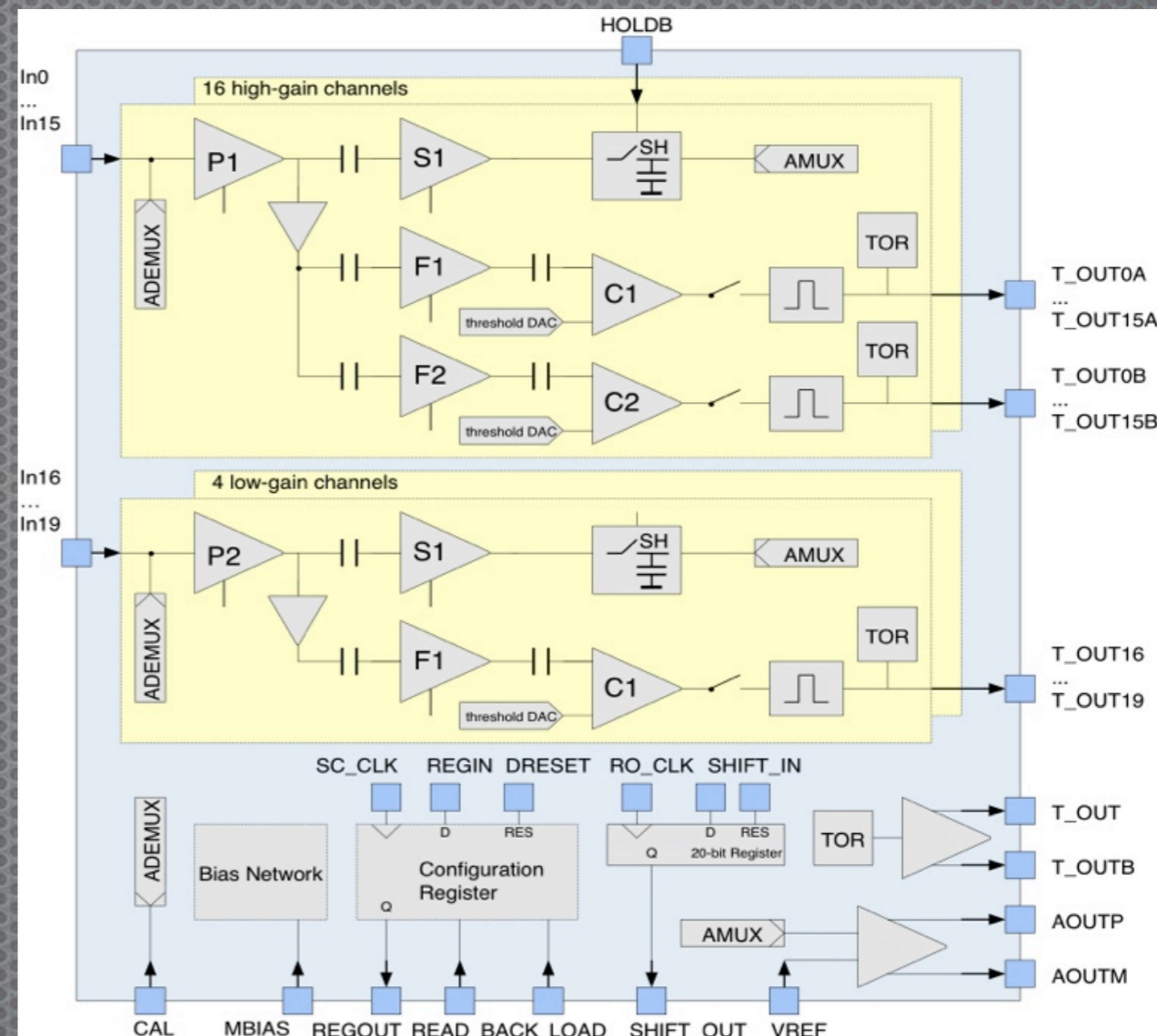
The IDE 3465 is an application specific integrated circuit (ASIC) that has been designed for the readout of the p-side of silicon detectors.

Supplier	IDEAS
Wafer fab	AMS
Technology	0.35 μm CMOS
Epitaxial layer	Yes
Metal Layers	4
Capacitor option	Double poly
Chip dimensions	6045 μm \times 7140 μm



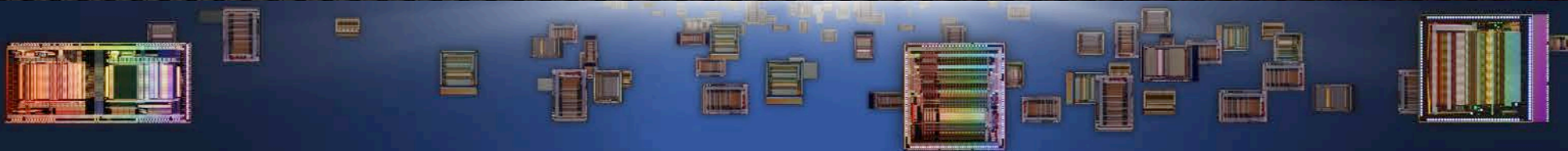
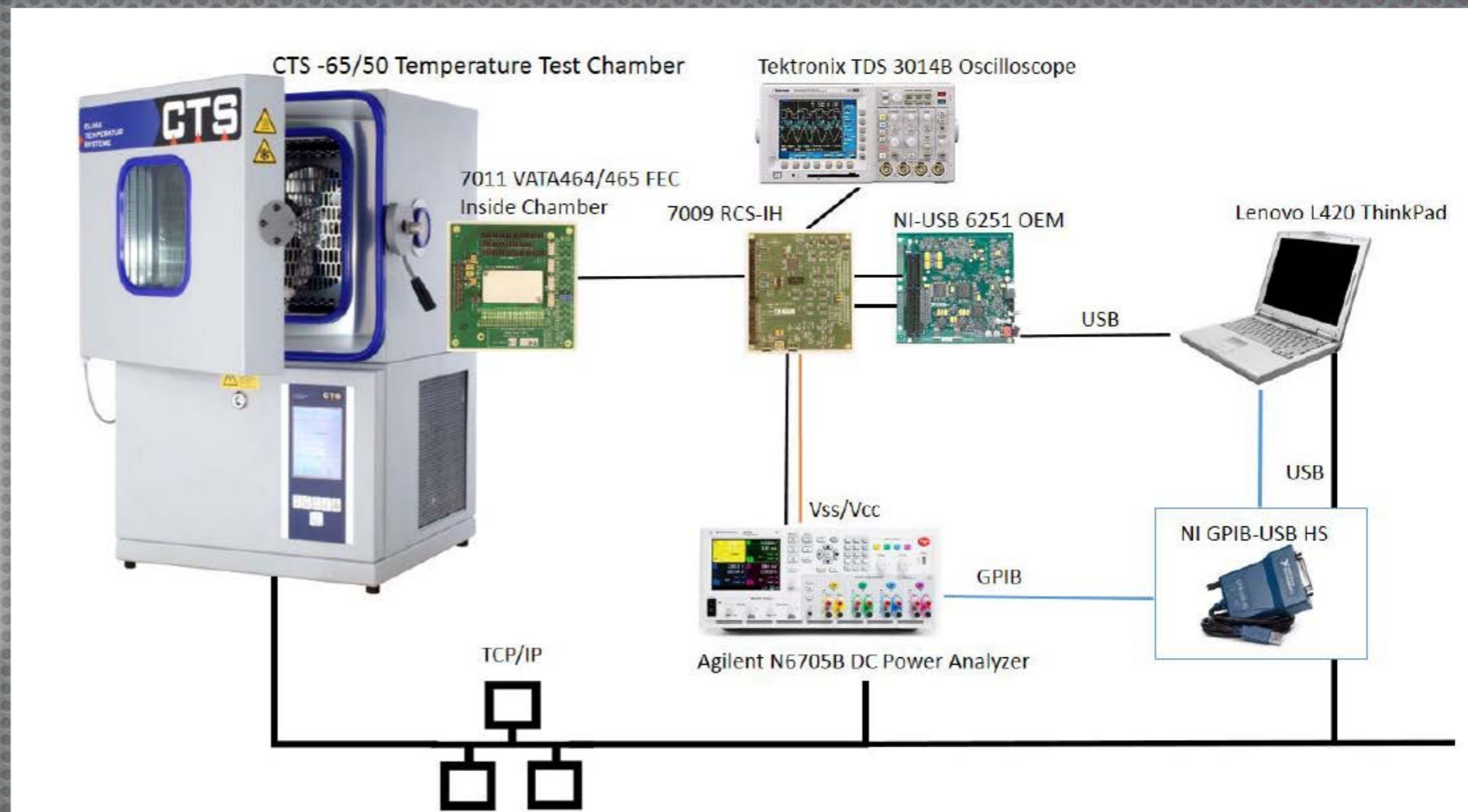
IDE 3465 – NGRM

20 charge sensitive inputs	< 2.6 pC in 16 high-gain channels < 26 pC in 4 low-gain channels
37 digital logic trigger outputs	32 outputs from the 2 comparators in the high-gain channels 4 outputs from the comparator in the low-gain channels 1 OR from all comparators
1 analogue output	Pulse height spectroscopy from all channels
Noise	0.45 fC ENC in high-gain channels 5 fC ENC in low-gain channels
Trigger threshold, minimum	1.5 fC and 71 fC in high-gain channels 150 fC in low-gain channels
Power	62.5 mW maximum, typical consumption 50 mW
Rate, maximum	> 1 Mcps/channel capability at the trigger outputs > 2.5 kcps/channel with analogue readout of all channels
Radiation tolerance	The chip is SEL immune (SEL LET _{th} >100 MeV/mg/cm ²) The chip is radiation tolerant by design and manufacture, with respect to single event upsets



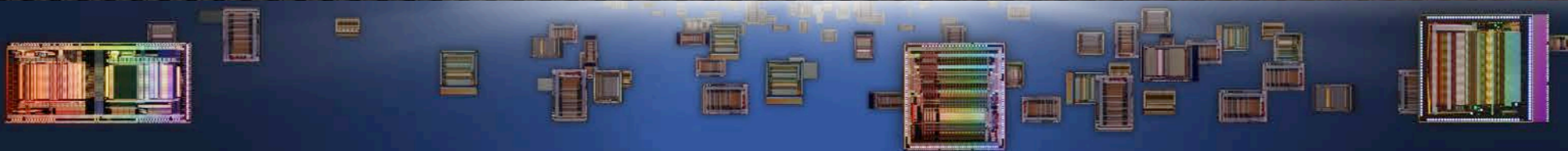
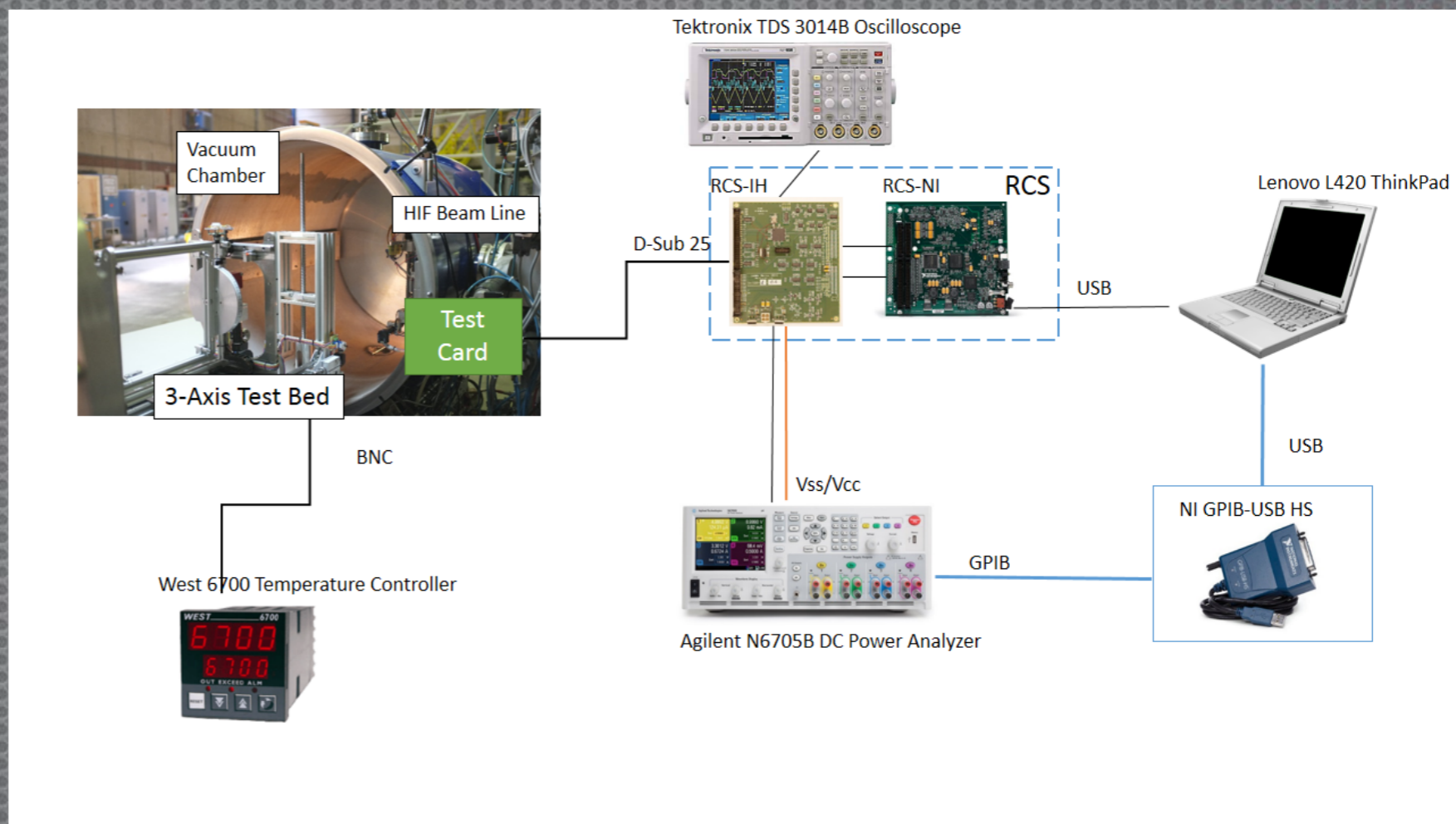
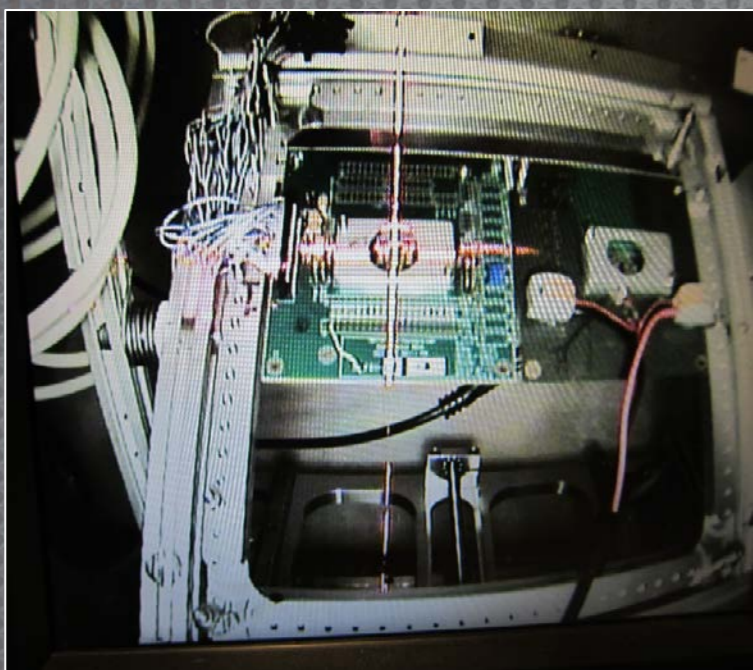
Design validation – temperature

Validated operating temperature -65°C to +40°C at IDEAS

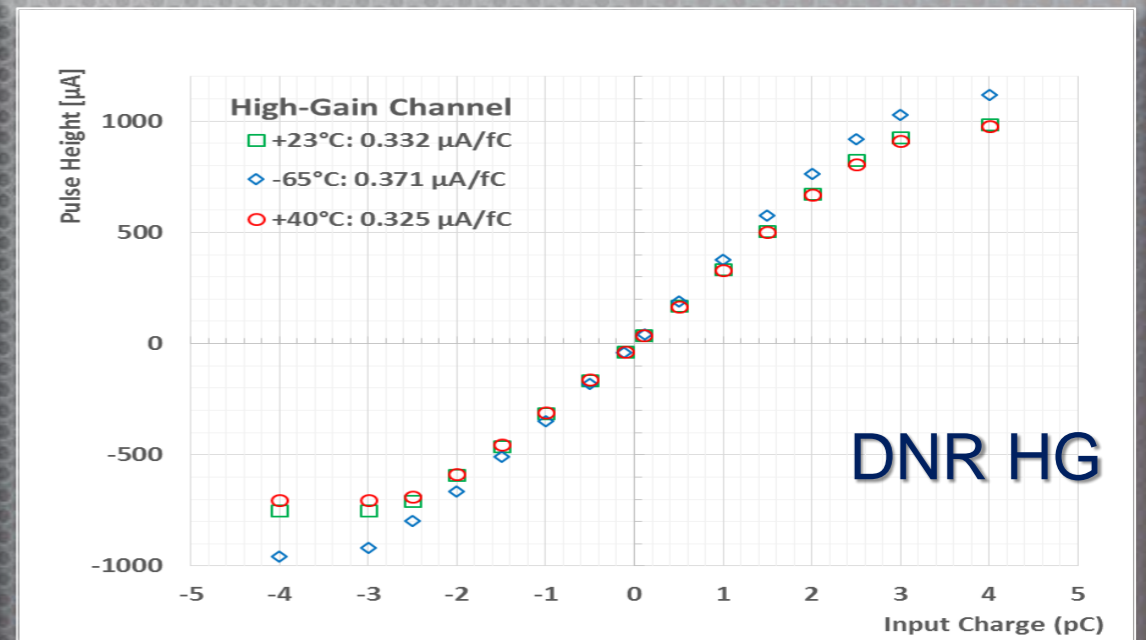
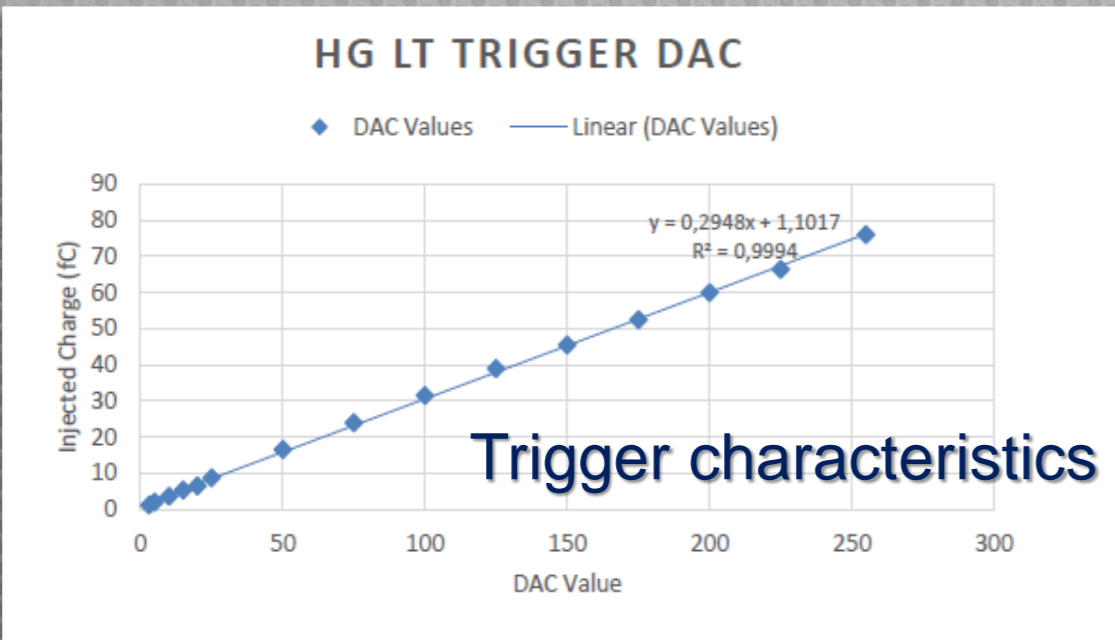
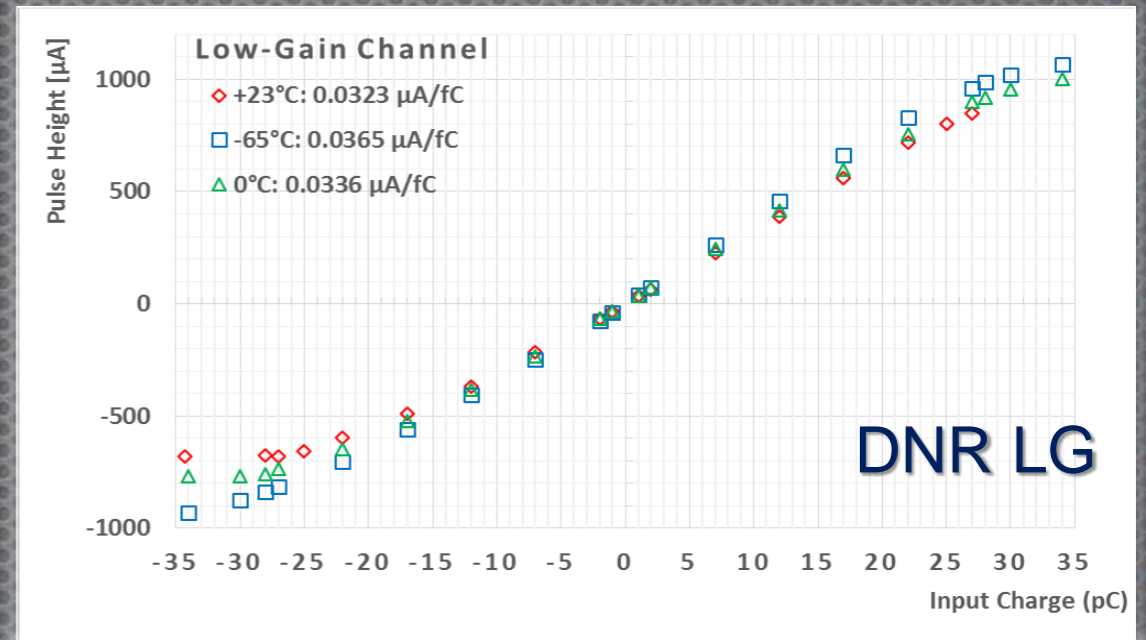
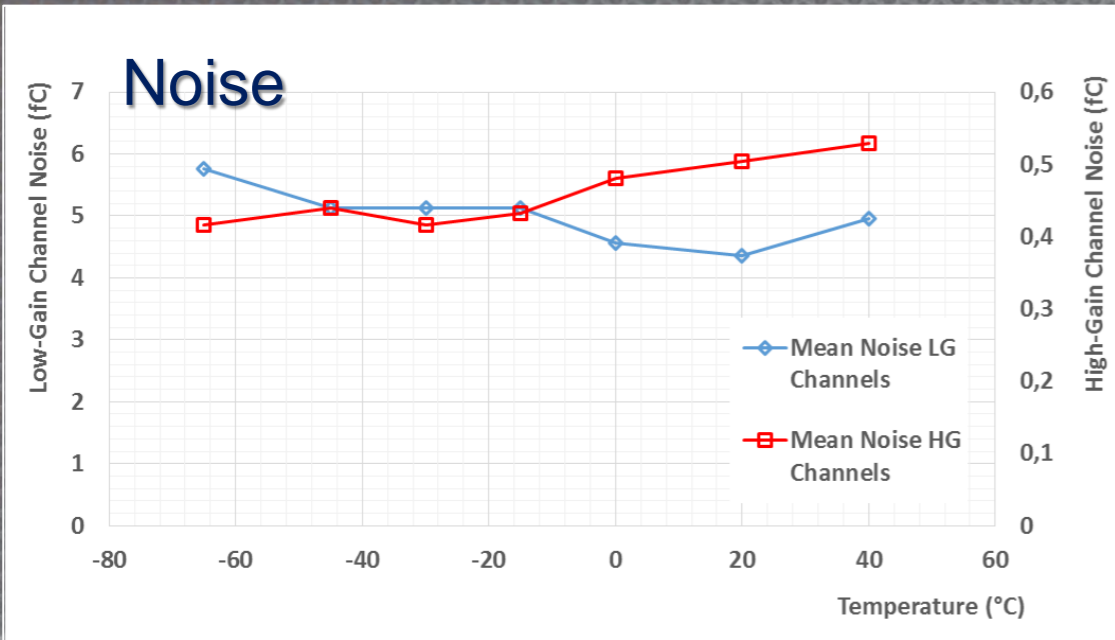


Design validation – radiation

SEE tests performed at UCL $SEL_{th} > 116 \text{ MeVcm}^2/\text{mg}$
80°C ASIC temperature in accordance with ESCC 25100



NGRM ASIC validation



IDE 3466 – RADEM

The IDE 3466 is an application specific integrated circuit (ASIC) for RADEM with heritage from IDE 3465.

Features

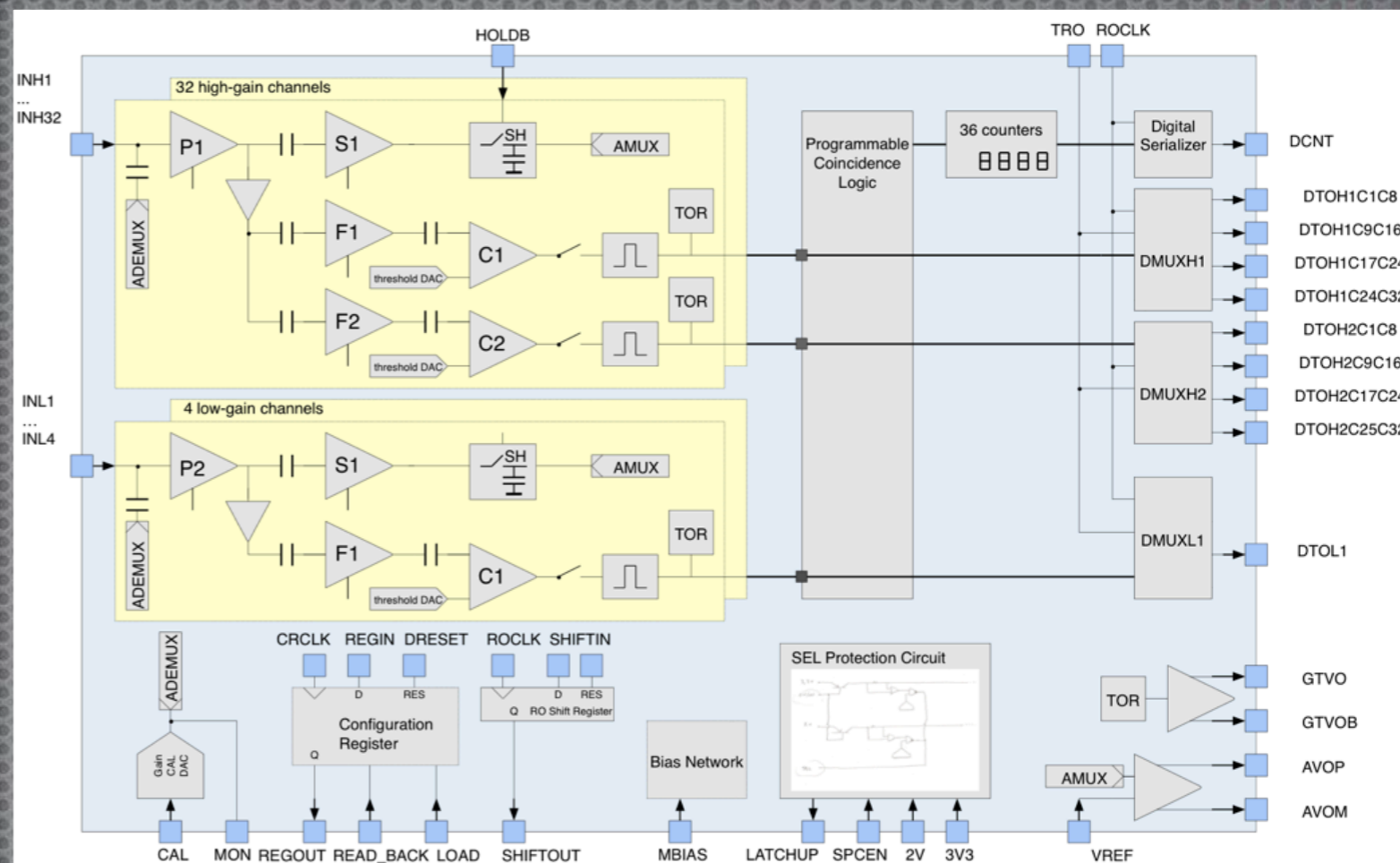
On-chip event counting

SEL protection circuit

32 HG channels and 4 LG channels

Dynamic range: 2.6 fC HG 26 fC LG

Radiation hard by design

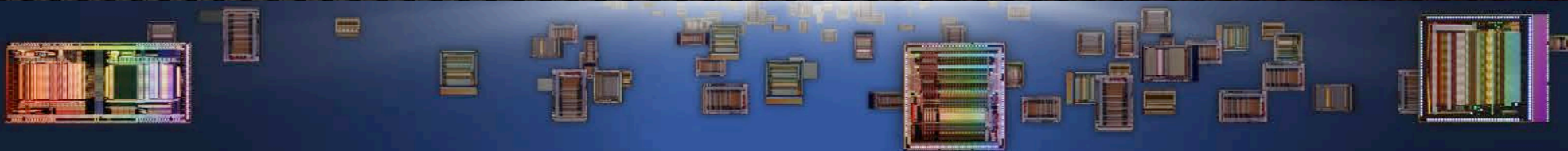


IDE 3466 – RADEM

Validation with functional, performance and operational testing

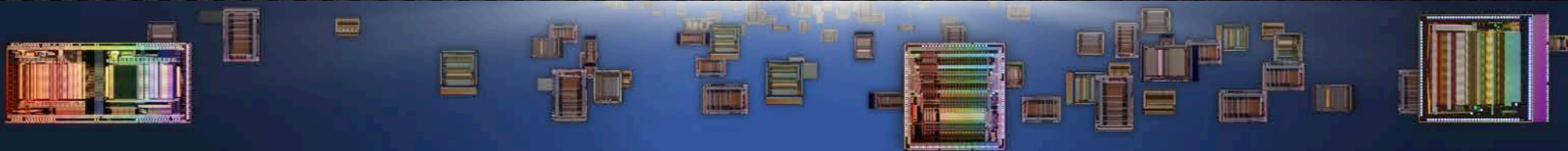
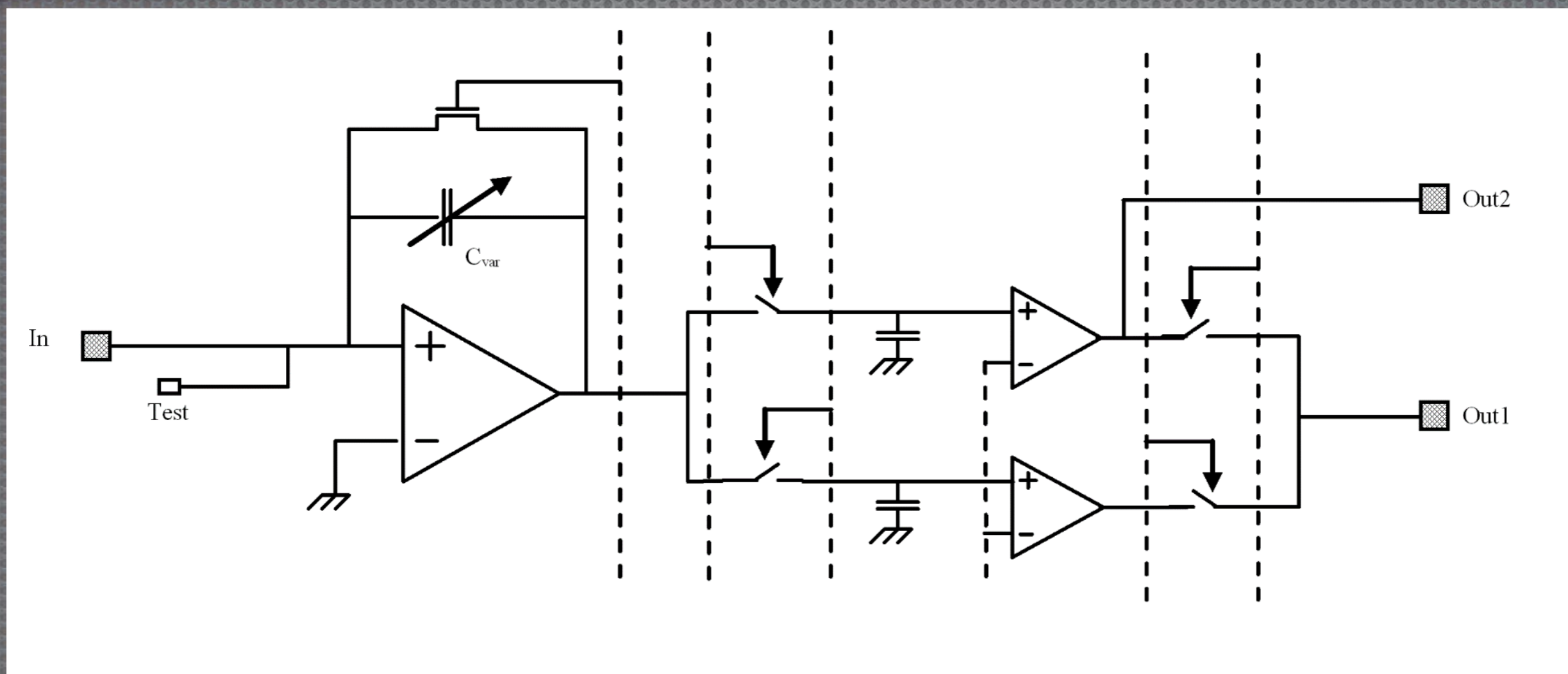
SEM testing in accordance with ESCC-21400

Radiation testing in accordance to ESCC-25100 and ESCC-22900



VAI – family ASICs

ASICs with current integrators



VA_SCM3.2

The VS_SCM3.2 is a current integrator ASIC designed to read out a variety of detectors

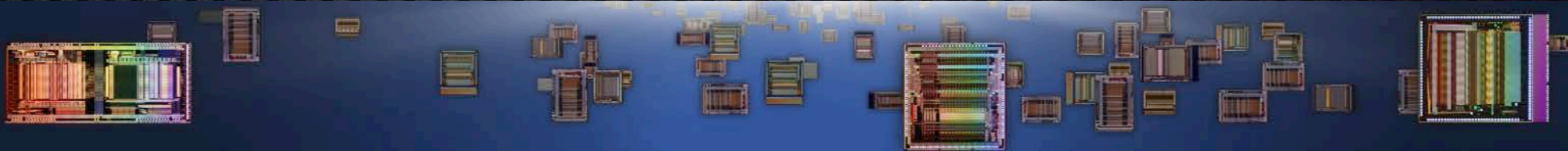
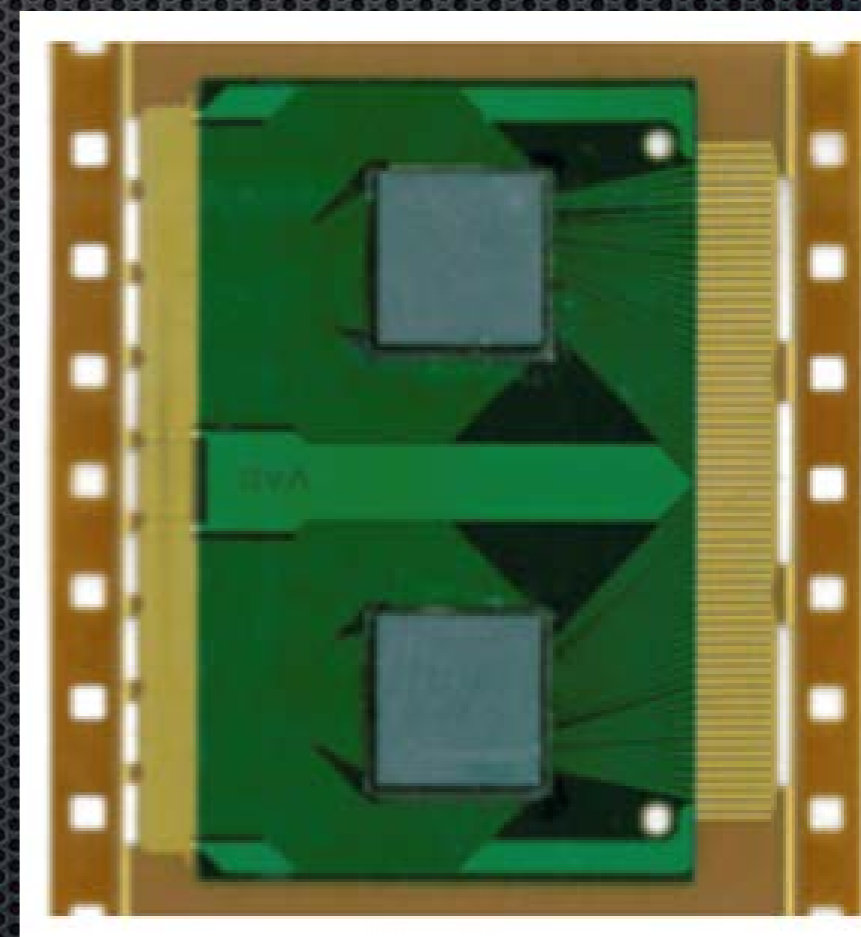
Continuous current integration mode

Correlated double sampling mode

128 input channels

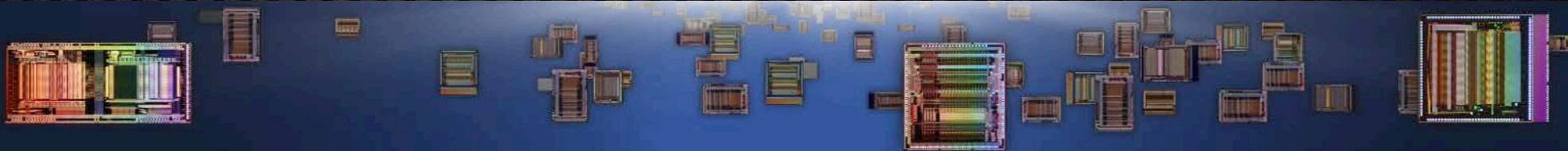
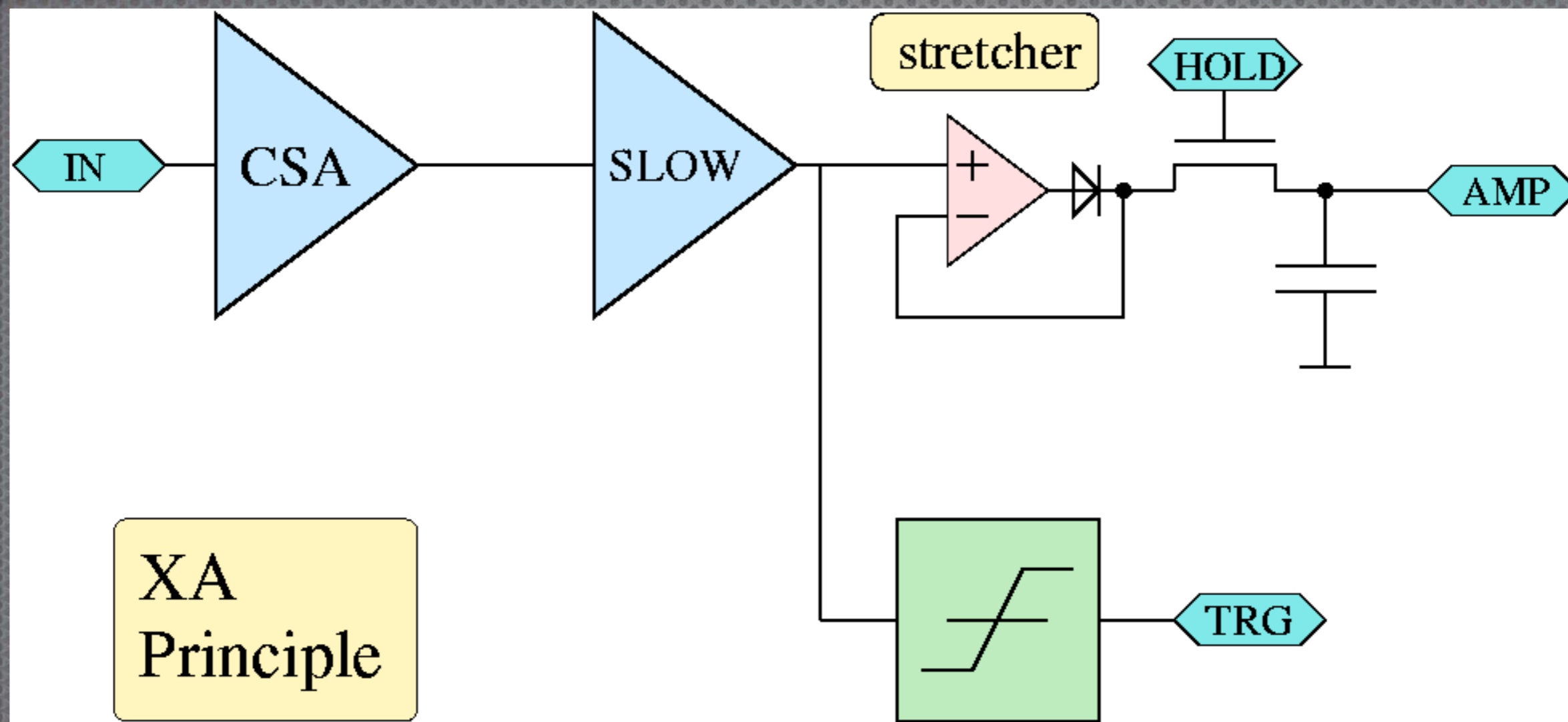
Multiple pre-amplifier gain settings

Dynamic range ± 20 pC



XA – family ASICs

ASICs for spectroscopy with on-chip trigger, self-triggering



XA1.83 – ASIM

The XA 1.83 is an application specific integrated circuit (ASIC) that has been designed for the readout of CZT pixelated radiation detectors

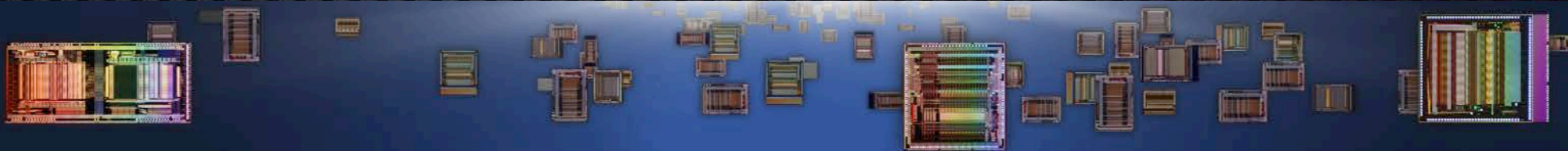
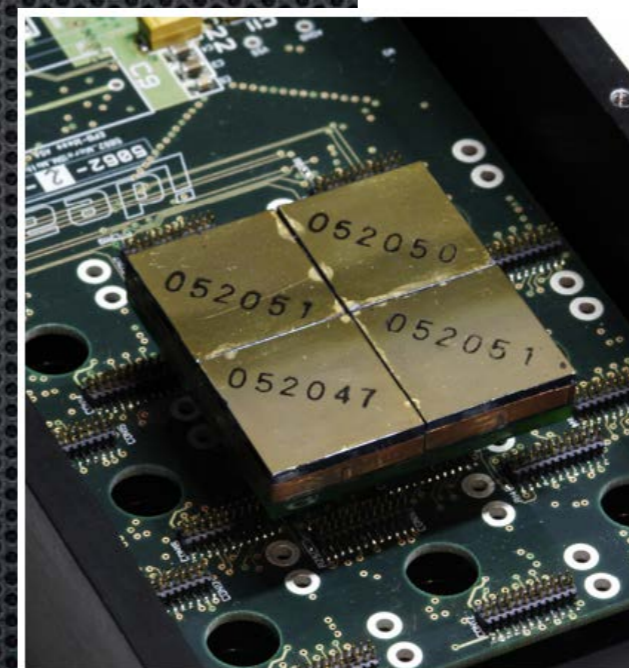
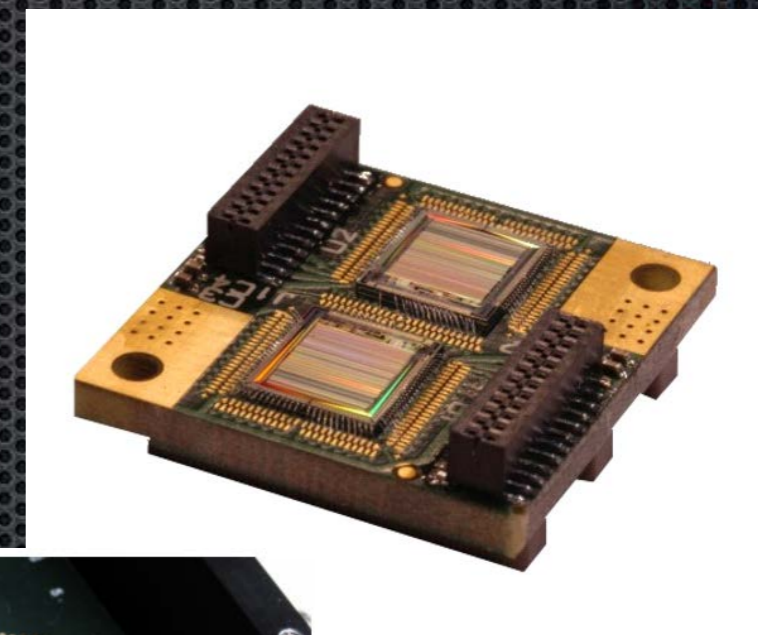
Each CZT pixel measures energy from 20 keV to 360 keV
A total of 128 ASICs (16384 channels) of XAs will be used in the Atmosphere Space Interaction Monitor (ASIM).

Trigger address encoding

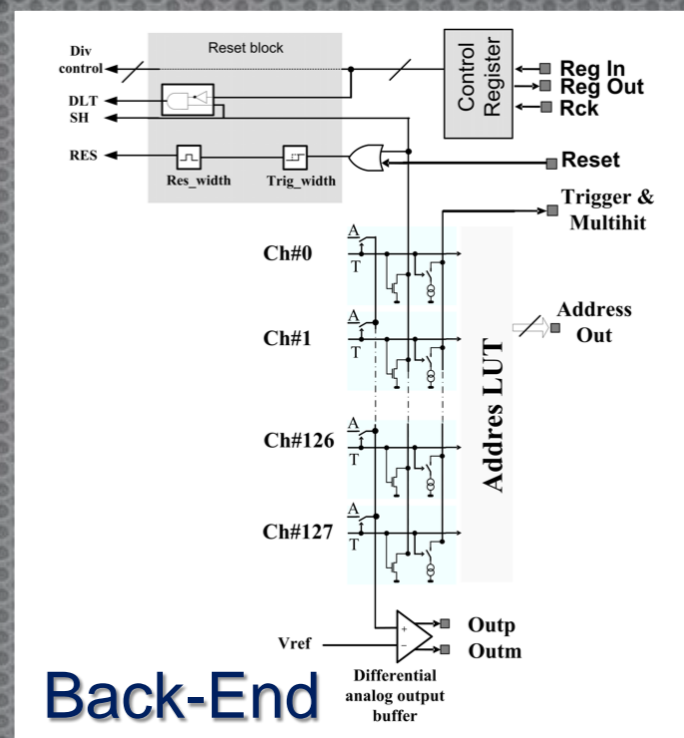
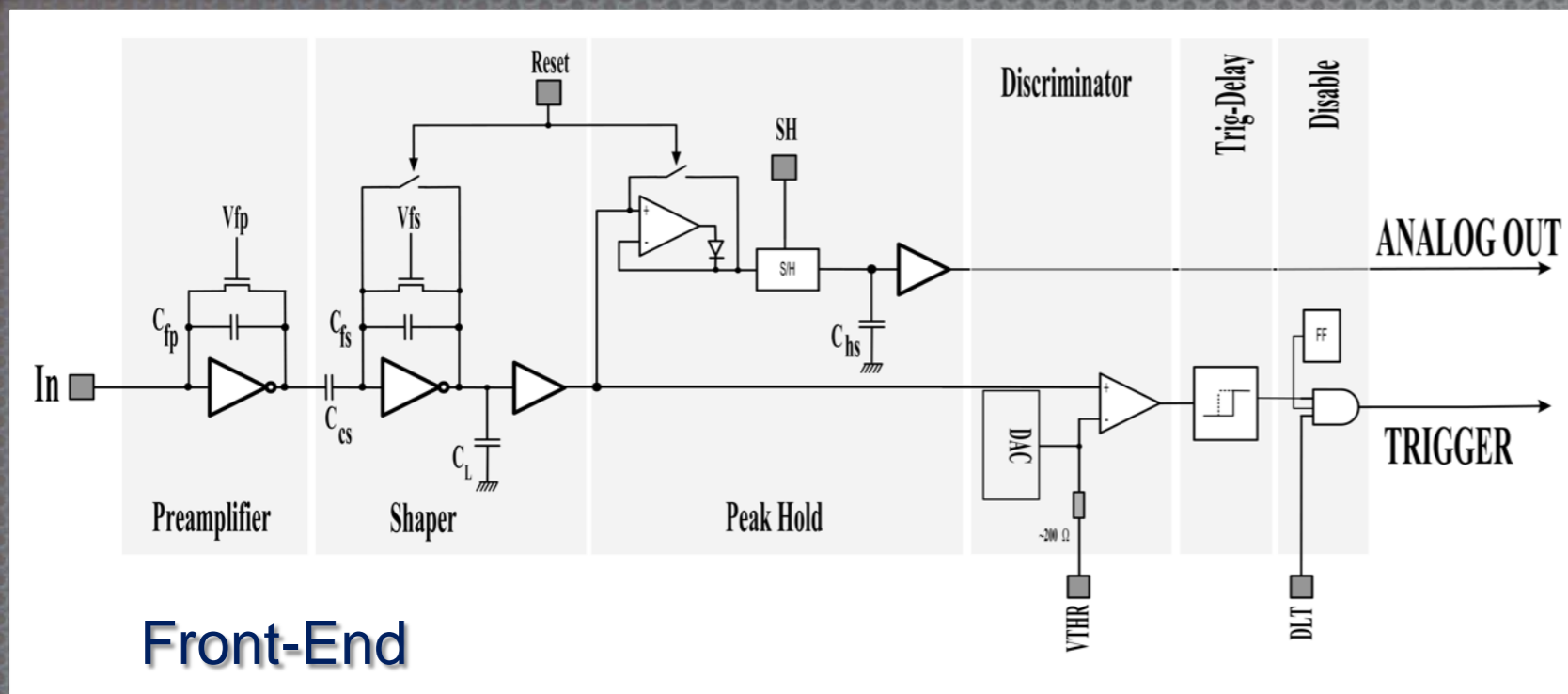
65536 channels can be daisy-chained

Temperature drift compensation

Also used in LumaGEM Molecular Breast Imaging camera

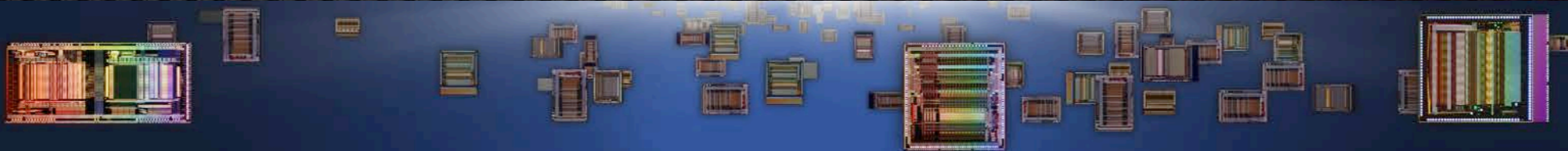
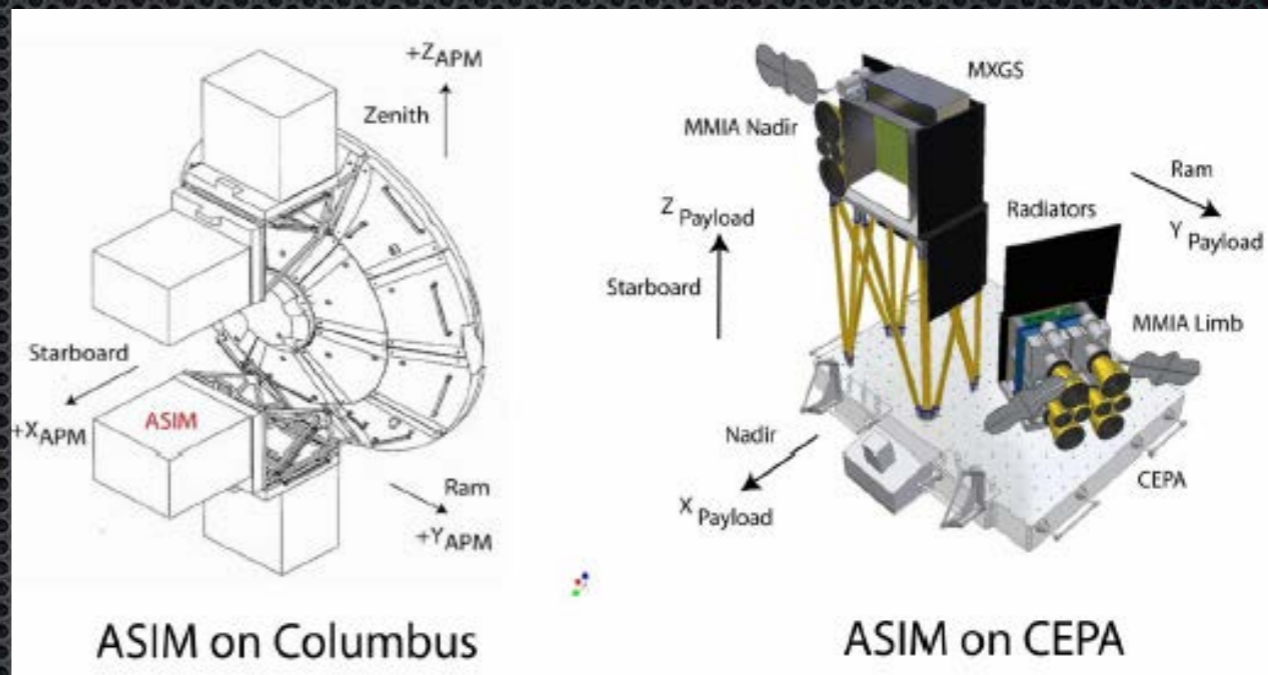


XA1.83



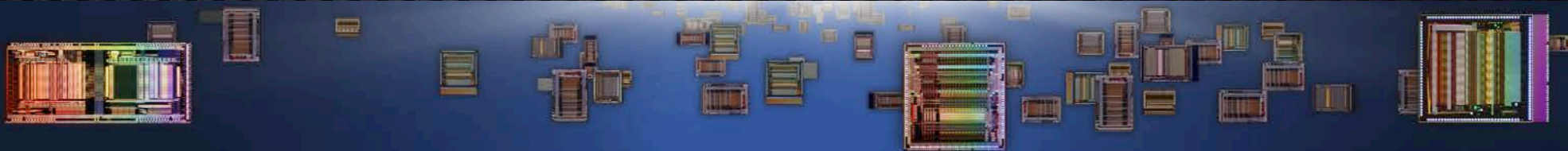
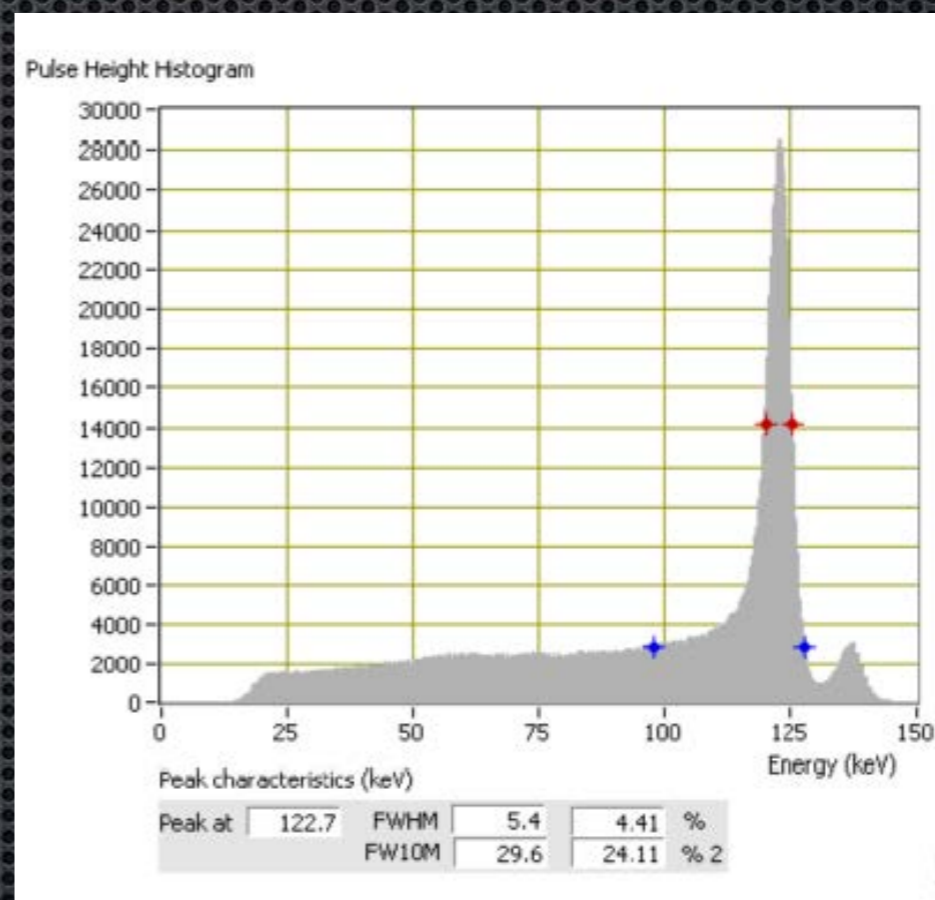
XA1.83

Parameter	Value	Comment
Number of Input Channels	128	Readout for 128 pixels
Input charge dynamic range	0 .. -12.5 fC	Negative charge, readout of anodes
Power consumption	0.5 mW/channel	64 mW total (nominal setting)
Electronic noise of CSA	130 e + 20 e/pF	At 0.5- μ s shaping time. Measured energy resolution is 5.4 keV FWHM at 122 keV in CZT pixels
Threshold	0.3 fC, negative charge	10 keV in CZT
Rate capability, maximum	20 kHz .. 100 kHz per ASIC	Highest rate tested with this ASIC is 20 kHz. Depending on system configuration, >100 kHz is expected to be possible
Detector Capacitance	0 pF .. 10 pF	Optimized for 4pF
Detector Leakage Current	0 nA .. - 100 nA	Positive current out of the preamplifiers



XA1.83

5.4 keV FWHM at Co-57 122 keV, all pixels summed.



IDE 4281

The IDE 4281 is an application specific integrated circuit (ASIC) that has been designed for the readout of CdTe/CZT radiation detectors in space.

Single photon spectroscopy of x-rays and γ -rays with energy between 3.5 keV and 140 keV @100 kHz per chip

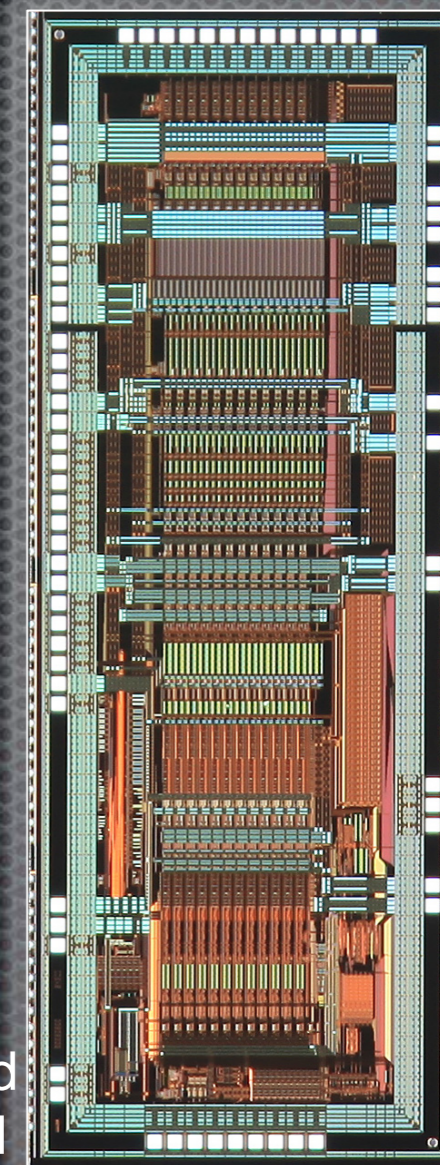
12 channels

Programmable peaking time

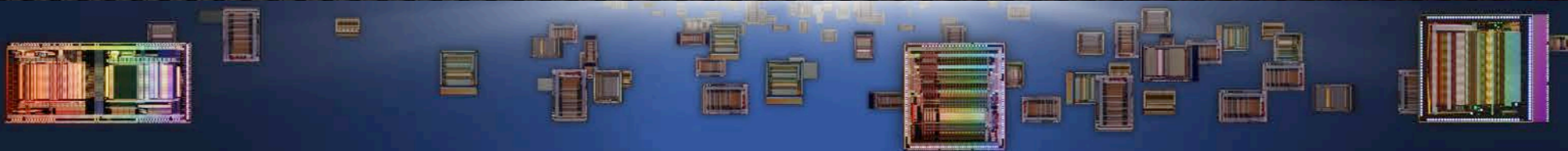
Trigger address encoding

19 mW idle/25 mW maximum

Radiation hard by design

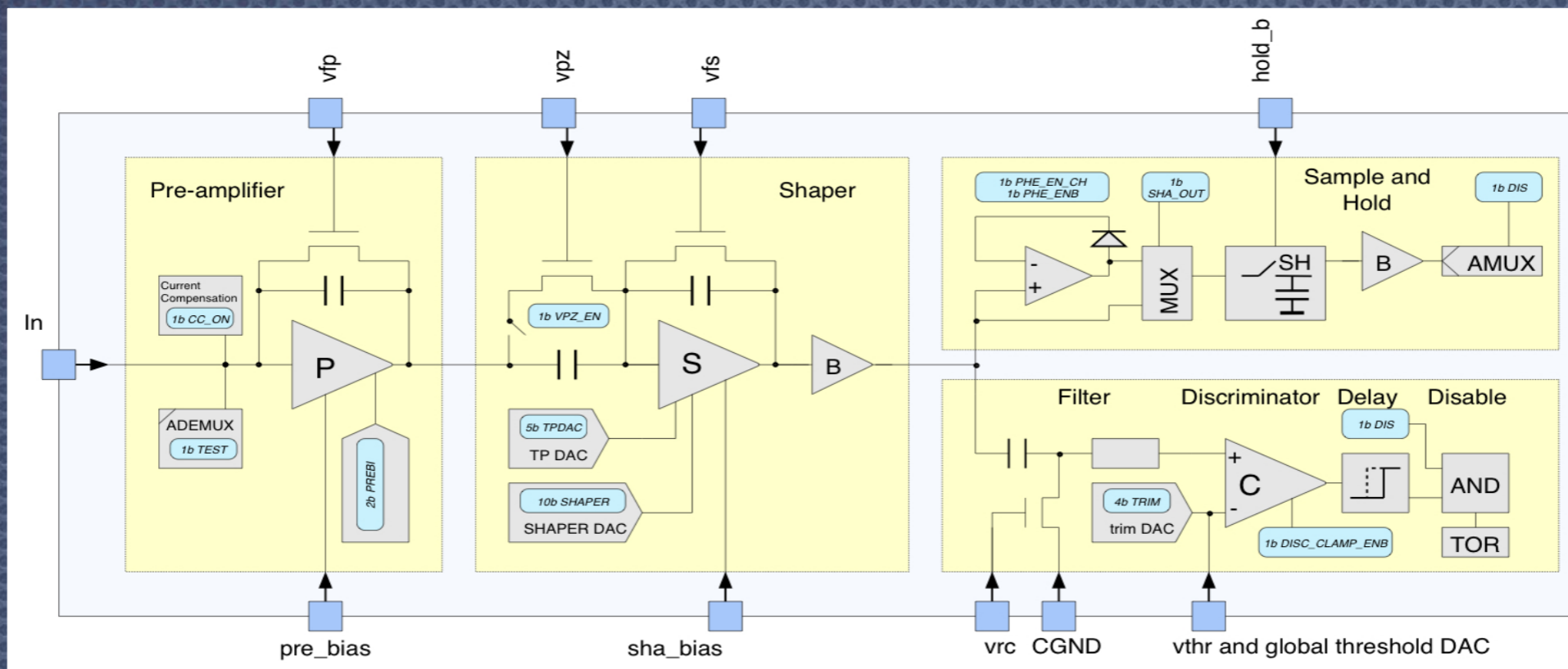


The ASIC was designed for the STIX detector unit. STIX is one of 10 instruments on board Solar Orbiter, a confirmed M-class mission of the European Space Agency to be launched in 2017. STIX has 32 pixelated CdTe detectors for detection of hard x-ray emissions from 4 keV to 150 keV. STIX foresees using the IdeF-X HD chip [Meuris et al., IEEE TNS, April 2008]. The IDE 4281 was an alternative chip solution for STIX.



IDE 4281

Channel Architecture



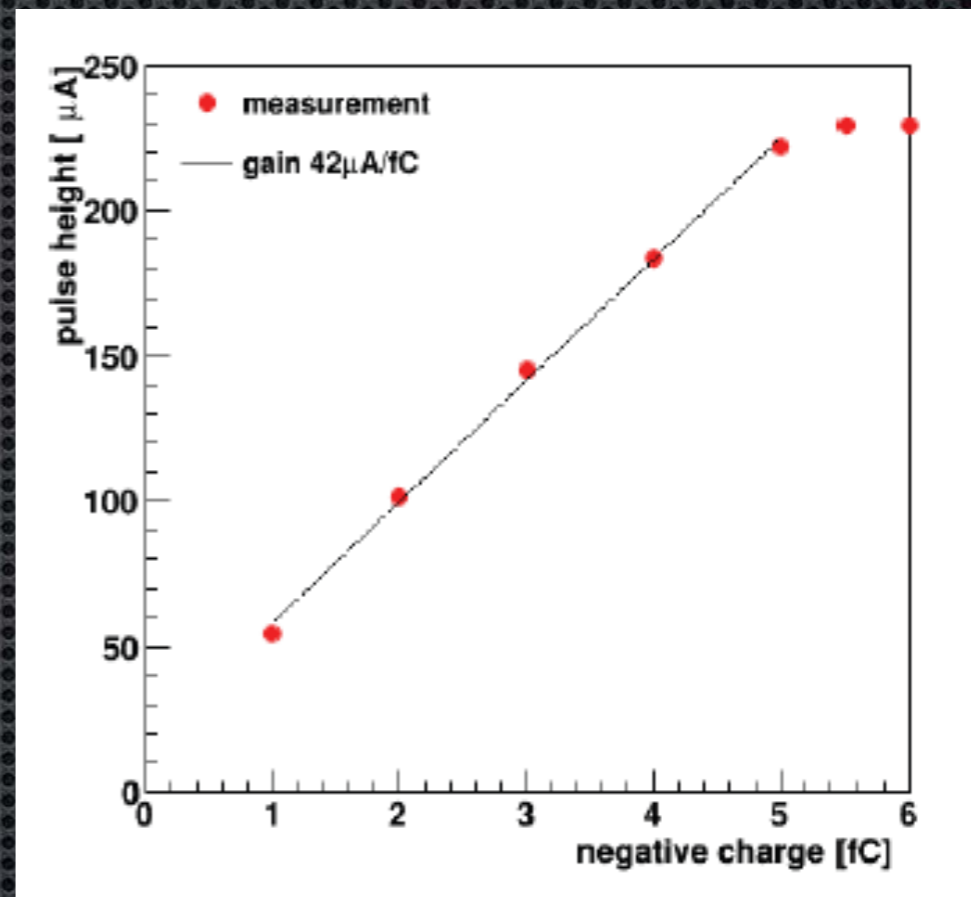
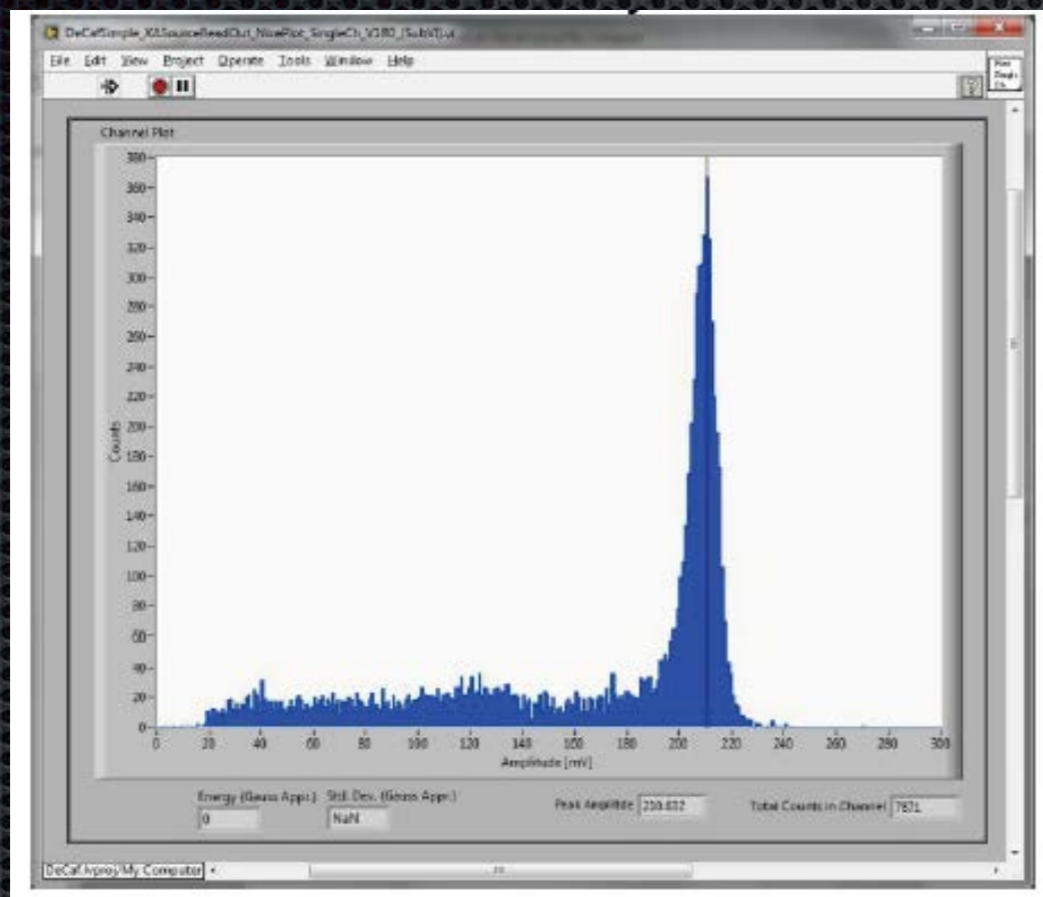
- Charge Sensitive Pre-amplifier (P)
- Programmable Shaper (S), Pole-Zero Cancellation
- Stretcher (peak-hold devices), sample and hold (SH)
- Analogue Multiplexer Readout (AMUX)
- Comparators (C), programmable reference
- Mono-stable Trigger Outputs, Trigger OR (TOR)

Radiation tolerant/hardened library

- Full custom guard rings against SEL
- Epitaxial layer process against SEL
- Triple redundant flip-flops correct for SEU
- Sub- μm CMOS technology improves TID
- SEL/SEU $\text{LET}_{\text{th}} > 67.7 \text{ MeVcm}^2/\text{mg}$



IDE 4281



Pulse height spectrum from a channel at +21°C, γ from Am-241, eV-Products CZT.

